

AA022P1-00

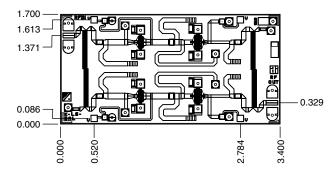
Features

- Single Bias Supply Operation (6 V)
- 14 dB Typical Small Signal Gain
- 24.5 dBm Typical P_{1 dB} Output Power at 23 GHz
- 0.25 µm Ti/Pd/Au Gates
- 100% On-Wafer RF and DC Testing
- 100% Visual Inspection to MIL-STD-883 MT 2010

Description

Alpha's two-stage balanced K band GaAs MMIC power amplifier has a typical $P_{1 \ dB}$ of 24.5 dBm with 13 dB associated gain and 11% power added efficiency at 23 GHz. The chip uses Alpha's proven 0.25 μ m MESFET technology, and is based upon MBE layers and electron beam lithography for the highest uniformity and repeatability. The FETs employ surface passivation to ensure a rugged reliable part with through-substrate via holes and gold-based backside metallization to facilitate a conductive epoxy die attach process. All chips are screened for small signal S-parameters and power characteristics prior to shipment for guaranteed performance. A broad range of applications exist in both the high reliability and commercial areas where high power and gain are required.

Chip Outline



Dimensions indicated in mm. All DC (V) pads are 0.1×0.1 mm and RF In, Out pads are 0.07 mm wide. Chip thickness = 0.1 mm.

Absolute Maximum Ratings

Characteristic	Value		
Operating Temperature (T _C)	-55°C to +90°C		
Storage Temperature (T _{ST})	-65°C to +150°C		
Bias Voltage (V _D)	7 V _{DC}		
Power In (P _{IN})	22 dBm		
Junction Temperature (T _J)	175°C		

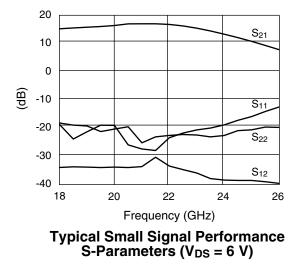
Electrical Specifications at $25^{\circ}C$ (V_{DS} = 6 V)

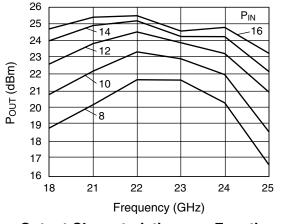
Parameter	Condition	Symbol	Min.	Typ. ²	Max.	Unit
Drain Current (at Saturation)		I _{DS}		300	390	mA
Small Signal Gain	F = 18–23 GHz	G	12	14		dB
Input Return Loss	F = 18–23 GHz	RL		-15	-10	dB
Output Return Loss	F = 18–23 GHz	RLO		-17	-10	dB
Output Power at 1 dB Gain Compression	F = 23 GHz	P _{1 dB}	22	24.5		dBm
Saturated Output Power	F = 23 GHz	P _{SAT}	24	25.5		dBm
Gain at Saturation	F = 23 GHz	G _{SAT}		13		dB
Thermal Resistance ¹		Θ _{JC}		39		°C/W

1. Calculated value based on measurement of discrete FET.

2. Typical represents the median parameter value across the specified

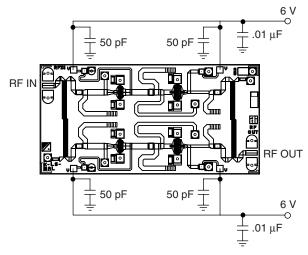
Typical Performance Data





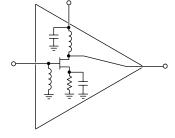
Output Characteristics as a Function of Frequency and Input Drive Level $(V_{DS} = 6 V)$

Bias Arrangement



For biasing on, adjust $V_{\rm DS}$ from zero to the desired value (6 V recommended). For biasing off, reverse the biasing on procedure.

Circuit Schematic



Detail A

